



APTM10DAM02G Information

Heisener.com

Part Number APTM10DAM02G

Manufacturer Microsemi Corporation

Category Discrete Semiconductor Products

Transistors - FETs, MOSFETs - Single

Description MOSFET N-CH 100V 495A SP6

Package SP6

For the pricing/inventory/lead time, please contact

us

For Reference Only

Website: https://www.heisener.com
E-mail: salesdept@heisener.com



Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.









APTM10DAM02G Specifications

Manufacturer Part Number	APTM10DAM02G
Manufacturer	Microsemi Corporation
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Single
Package	SP6
Series	-
FET Type	N-Channel
Technology	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss)	100V
Current - Continuous Drain (Id) @ 25°C	495A
Drive Voltage (Max Rds On, Min Rds On)	10V
Vgs(th) (Max) @ Id	4V @ 10mA
Gate Charge (Qg) (Max) @ Vgs	1360nC @ 10V
Input Capacitance (Ciss) (Max) @ Vds	40000pF @ 25V
Vgs (Max)	±30V
FET Feature	-
Power Dissipation (Max)	1250W (Tc)
Rds On (Max) @ Id, Vgs	2.5 mOhm @ 200A, 10V
Operating Temperature	-40°C ~ 150°C (TJ)
Mounting Type	Chassis Mount
Supplier Device Package	SP6
Package / Case	SP6
	Report errors?

APTM10DAM02G Guarantees



Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

APTM10DAM02G Payment Methods



















APTM10DAM02G Shipping Methods













If you have any question about APTM10DAM02G, please do not hesitate to contact us!

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